

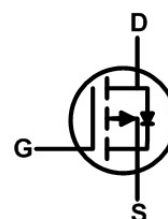
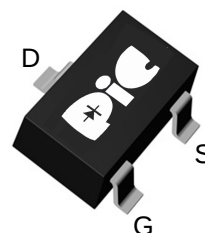
## ➤ General Description

This PAP2303R P-Channel enhancement mode power field effect transistor is the high density trench technology and this advanced technology can provide excellent  $R_{ds(On)}$  performance and efficiency for power switching and load switching application., this device also comply with the RoHS and Green Product requirement with full function reliability approved.

## ➤ Feature

- Super high density cell design for extremely low  $R_{DS(ON)}$
- Exceptional on-resistance and maximum DC current capability
- SOT-323 package design

## ➤ SOT-323



## ➤ Application

- Net Working System
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories
- Battery Operated Systems
- Power Supply Converter Circuits
- Load/Power Switching Smart Phones, Pagers

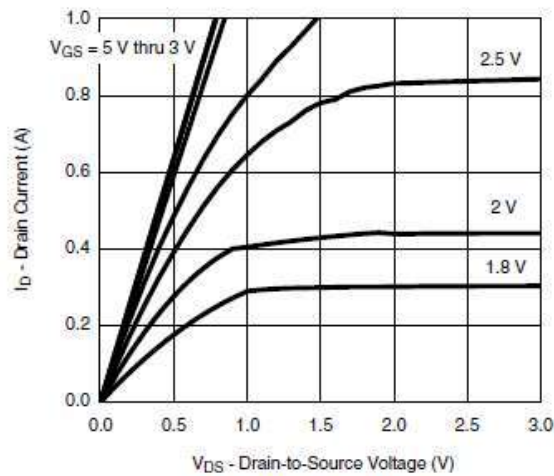
## ➤ Absolute Maximum Ratings

| Parameter                                     | Symbol          | Value                    | Unit         |
|-----------------------------------------------|-----------------|--------------------------|--------------|
| Drain-Source Voltage                          | $V_{DSS}$       | -20                      | V            |
| Gate -Source Voltage                          | $V_{GSS}$       | $\pm 12$                 | V            |
| Continuous Drain Current( $T_J=150^\circ C$ ) | $I_D$           | $T_A=25^\circ C$<br>-1.0 | A            |
|                                               |                 | $T_A=70^\circ C$<br>-0.6 |              |
| Pulsed Drain Current                          | $I_{DM}$        | -6                       | A            |
| Continuous Source Current(Diode Conduction)   | $I_S$           | -1                       | A            |
| Power Dissipation                             | $P_D$           | $T_A=25^\circ C$<br>0.35 | W            |
|                                               |                 | $T_A=70^\circ C$<br>0.22 |              |
| Operating Junction Temperature                | $T_J$           | 150                      | $^\circ C$   |
| Storage Temperature Range                     | $T_{STG}$       | -55/150                  | $^\circ C$   |
| Thermal Resistance-Junction to Ambient        | $R_{\theta JA}$ | 120                      | $^\circ C/W$ |

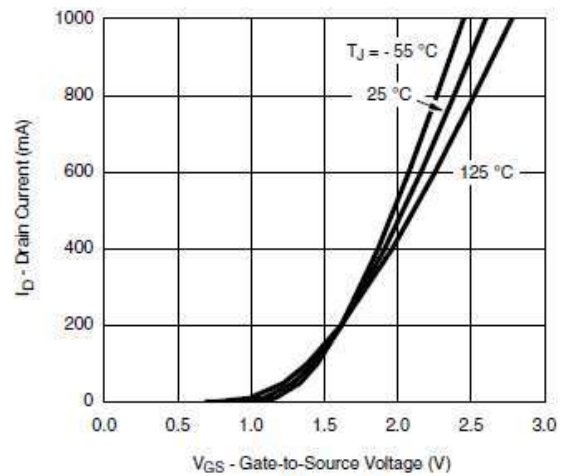
➤ **Electrical Characteristics ( $T_A=25^\circ C$  Unless otherwise noted)**

| Parameter                       | Symbol        | Conditions                                                                  | Min. | Typ  | Max.      | Unit       |
|---------------------------------|---------------|-----------------------------------------------------------------------------|------|------|-----------|------------|
| <b>Static</b>                   |               |                                                                             |      |      |           |            |
| Drain-Source Breakdown Voltage  | $V_{(BR)DSS}$ | $V_{GS}=0V, I_D=-250\mu A$                                                  | -20  |      |           | V          |
| Gate Threshold Voltage          | $V_{GS(th)}$  | $V_{DS}=V_{GS}, I_D=-250\mu A$                                              | -0.4 |      | -1.0      |            |
| Gate Leakage Current            | $I_{GSS}$     | $V_{DS}=0V, V_{GS}=\pm 12V$                                                 |      |      | $\pm 100$ | nA         |
| Zero Gate Voltage Drain Current | $I_{DSS}$     | $V_{DS}=-20V, V_{GS}=0V$                                                    |      |      | -1        | uA         |
|                                 |               | $V_{DS}=-20V, V_{GS}=0V$<br>$T_J=85^\circ C$                                |      |      | -5        |            |
| On-State Drain Current          | $I_{D(on)}$   | $V_{DS} \geq 5V, V_{GS}=4.5V$                                               | 0.7  |      |           | A          |
| Drain-Source On-Resistance      | $R_{DS(on)}$  | $V_{GS}=-4.5V, I_D=-1.8A$                                                   |      | 500  | 600       | m $\Omega$ |
|                                 |               | $V_{GS}=-2.5V, I_D=-1.5A$                                                   |      | 700  | 800       |            |
|                                 |               | $V_{GS}=-1.8V, I_D=-1.2A$                                                   |      | 1000 | 1300      |            |
| Forward Transconductance        | $g_{FS}$      | $V_{DS}=-10V, I_D=-0.4A$                                                    |      | 1    |           | S          |
| Diode Forward Voltage           | $V_{SD}$      | $I_S=-0.15A, V_{GS}=0V$                                                     |      | 0.65 | 1.2       | V          |
| <b>Dynamic</b>                  |               |                                                                             |      |      |           |            |
| Input Capacitance               | $C_{iss}$     | $V_{DS}=-10V, V_{GS}=0V$<br>$f=1MHz$                                        |      | 70   | 100       | pF         |
| Output Capacitance              | $C_{oss}$     |                                                                             |      | 20   |           |            |
| Reverse Transfer Capacitance    | $C_{rss}$     |                                                                             |      | 10   |           |            |
| Total Gate Charge               | $Q_g$         | $V_{DS}=-10V, V_{GS}=-4.5V$<br>$I_D=-0.25A$                                 |      | 1.0  | 1.3       | nC         |
| Gate-Source Charge              | $Q_{gs}$      |                                                                             |      | 0.1  |           |            |
| Gate-Drain Charge               | $Q_{gd}$      |                                                                             |      | 0.3  |           |            |
| Turn-On Time                    | $t_{d(on)}$   | $V_{DD}=-10V, R_L=30\Omega$<br>$I_D=-0.2A, V_{GEN}=-4.5V$<br>$R_G=10\Omega$ |      | 10   | 15        | ns         |
|                                 | $t_r$         |                                                                             |      | 10   | 15        |            |
| Turn-Off Time                   | $t_{d(off)}$  |                                                                             |      | 40   | 60        |            |
|                                 | $t_f$         |                                                                             |      | 30   | 50        |            |

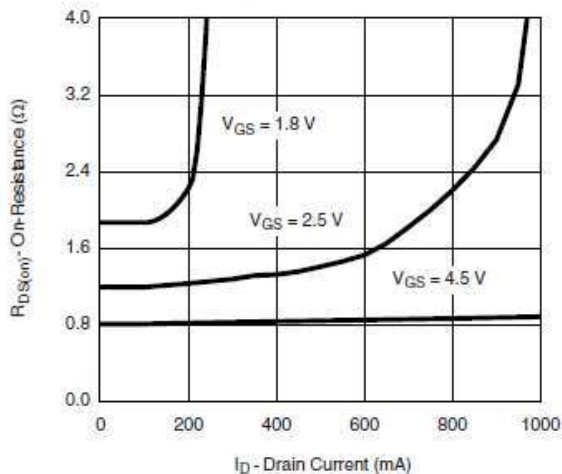
## ➤ Typical Characteristics



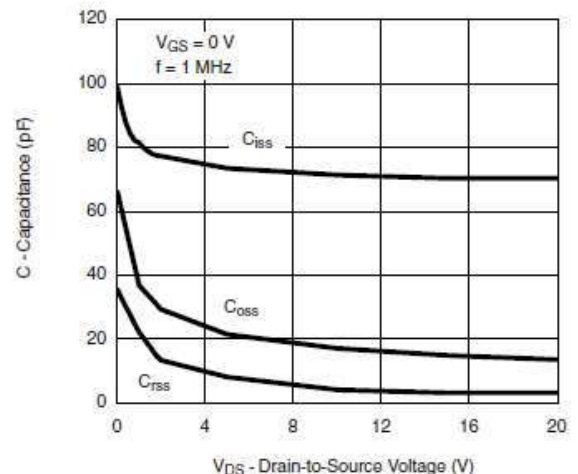
**Output Characteristics**



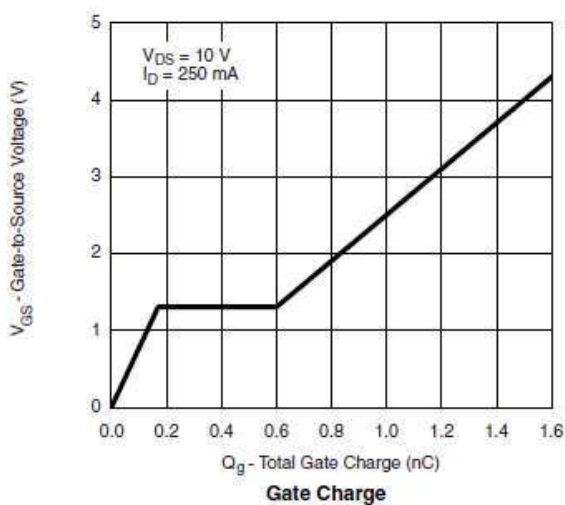
**Transfer Characteristics**



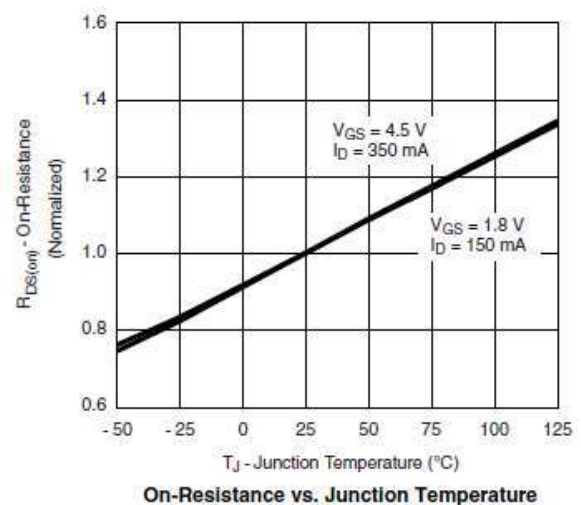
**On-Resistance vs. Drain Current**



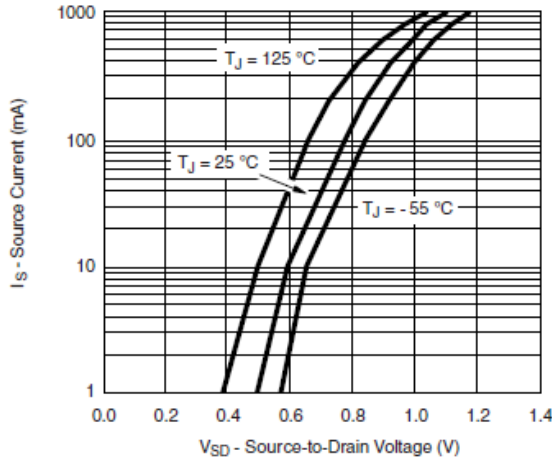
**Capacitance**



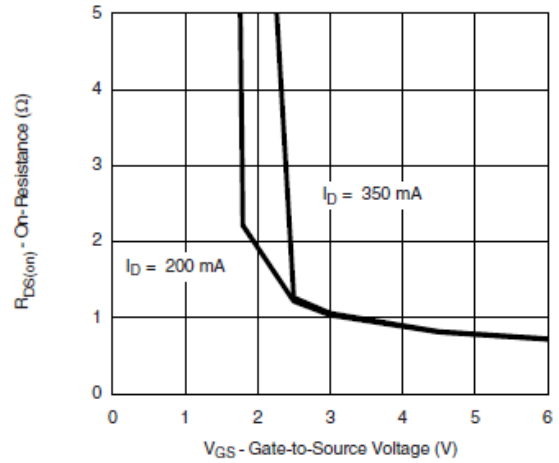
**Gate Charge**



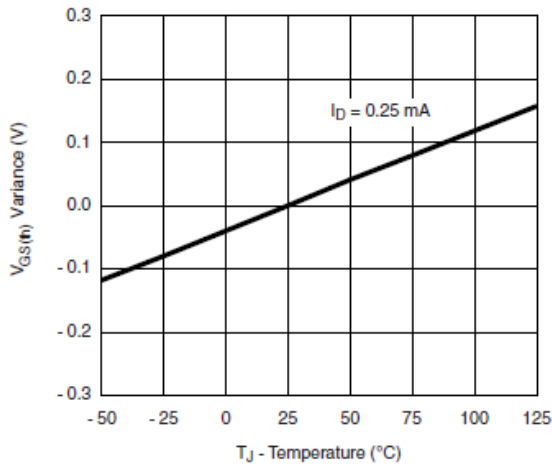
**On-Resistance vs. Junction Temperature**



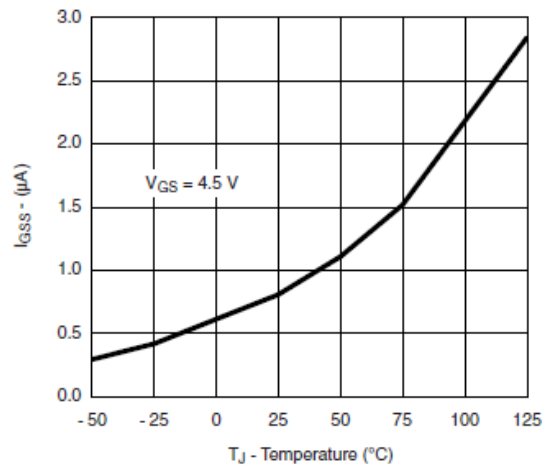
Source-Drain Diode Forward Voltage



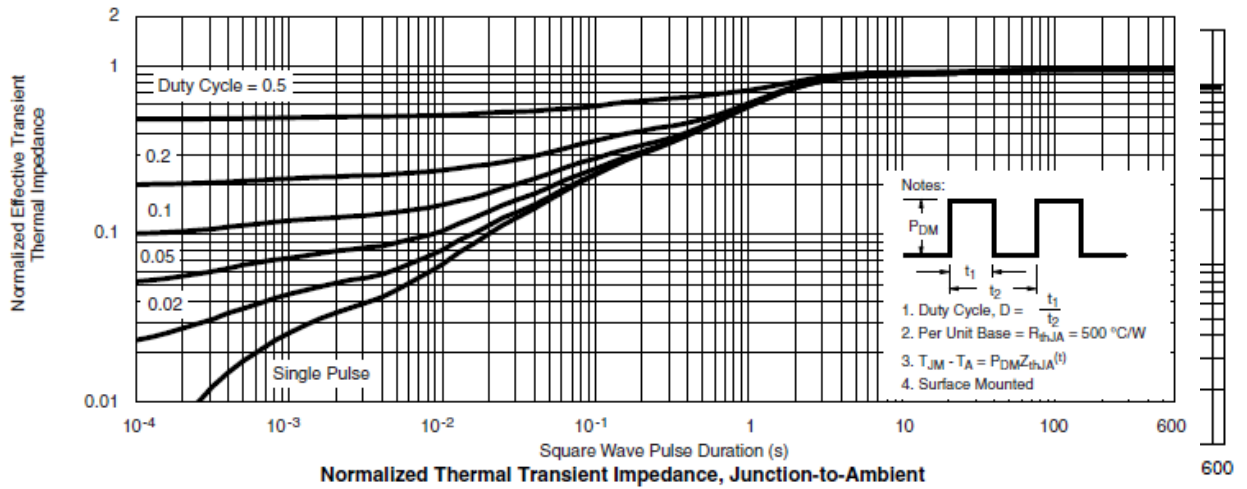
On-Resistance vs. Gate-to-Source Voltage



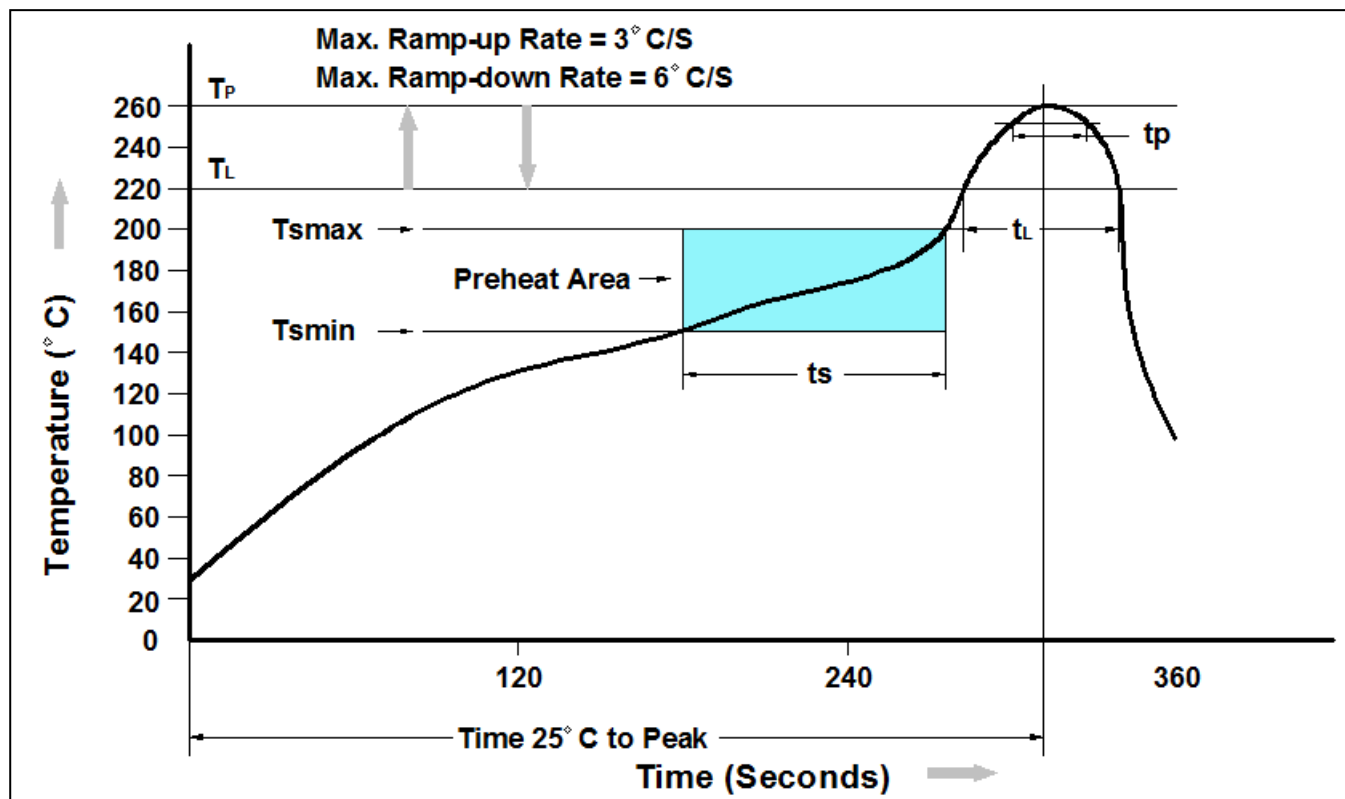
Threshold Voltage Variance vs. Temperature



$I_{GSS}$  vs. Temperature



## ➤ Recommend IR Reflow Soldering Thermal Profile

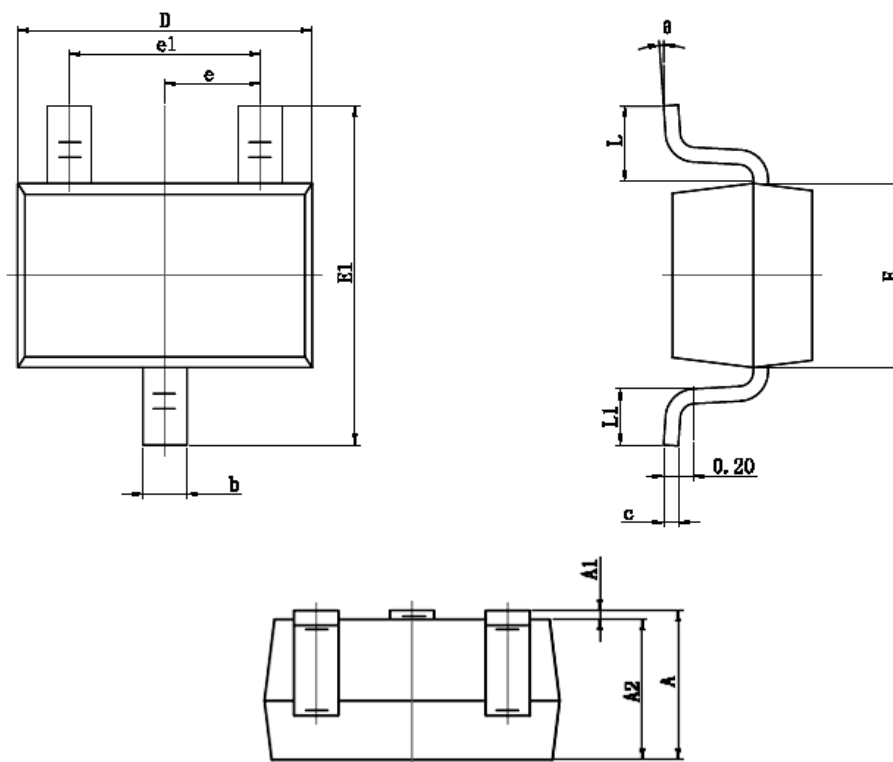


| Profile Feature                                      | Pb-Free Assembly Profile |
|------------------------------------------------------|--------------------------|
| Temperature Min. ( $T_{smin}$ )                      | 150°C                    |
| Temperature Max. ( $T_{smax}$ )                      | 200°C                    |
| Time ( $t_s$ ) from ( $T_{smin}$ to $T_{smax}$ )     | 60-120 seconds           |
| Average Ramp-up Rate ( $t_L$ to $t_P$ )              | 3°C/second max.          |
| Liquidous Temperature ( $T_L$ )                      | 217°C                    |
| Time ( $t_L$ ) Maintained Above ( $T_L$ )            | 60 – 150 seconds         |
| Peak Temperature                                     | 260°C +0°C / -5°C        |
| Time ( $t_P$ ) within 5°C of actual Peak Temperature | 30 seconds               |
| Ramp-down Rate ( $T_P$ to $T_L$ )                    | 6°C/second max           |
| Time 25°C to Peak Temperature                        | 8 minutes max.           |

## ➤ Ordering Information

| Part Number | Description  | Quantity |
|-------------|--------------|----------|
| PAP2303R    | SOT-323 Reel | 3000 pcs |

## ➤ Package Information ( SOT-323 )



| Symbol   | Dimensions In Millimeters |       | Dimensions In Inches |       |
|----------|---------------------------|-------|----------------------|-------|
|          | Min                       | Max   | Min                  | Max   |
| A        | 0.900                     | 1.100 | 0.035                | 0.043 |
| A1       | 0.000                     | 0.100 | 0.000                | 0.004 |
| A2       | 0.900                     | 1.000 | 0.035                | 0.039 |
| b        | 0.200                     | 0.400 | 0.008                | 0.016 |
| c        | 0.080                     | 0.150 | 0.003                | 0.006 |
| D        | 2.000                     | 2.200 | 0.079                | 0.087 |
| E        | 1.150                     | 1.350 | 0.045                | 0.053 |
| E1       | 2.150                     | 2.450 | 0.085                | 0.096 |
| e        | 0.650 TYP                 |       | 0.026 TYP            |       |
| e1       | 1.200                     | 1.400 | 0.047                | 0.055 |
| L        | 0.525 REF                 |       | 0.021 REF            |       |
| L1       | 0.260                     | 0.460 | 0.010                | 0.018 |
| $\theta$ | 0°                        | 8°    | 0°                   | 8°    |

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